

**PLASTIC MEDIUM-POWER
COMPLEMENTARY SILICON TRANSISTORS**
...designed for general-purpose amplifier and low speed switching applications

FEATURES:

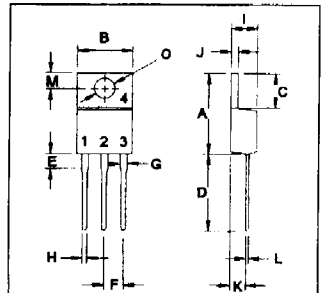
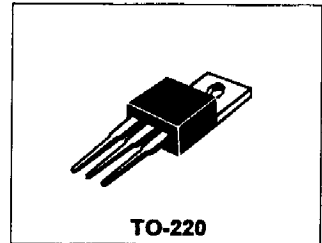
- * Collector-Emitter Sustaining Voltage-
 $V_{CE(sus)}$ = 60 V (Min) - TIP100, TIP105
= 80 V (Min) - TIP101, TIP106
= 100 V (Min) - TIP102, TIP107
- * Collector-Emitter Saturation Voltage
 $V_{CE(sat)}$ = 2.0 V (Max.) @ $I_C = 3.0$ A
- * Monolithic Construction with Built-in Base-Emitter Shunt Resistor

| | |
|---------------|---------------|
| NPN | PNP |
| TIP100 | TIP105 |
| TIP101 | TIP106 |
| TIP102 | TIP107 |

**8 AMPERE
DARLINGTON
COMPLEMENTARY SILICON
POWER TRANSISTORS
60-100 VOLTS
80 WATTS**

MAXIMUM RATINGS

| Characteristic | Symbol | TIP100 TIP105 | TIP101 TIP106 | TIP102 TIP107 | Unit |
|---|-------------------|------------------|------------------|------------------|--------------------------|
| Collector-Emitter Voltage | V_{CEO} | 60 | 80 | 100 | V |
| Collector-Base Voltage | V_{CBO} | 60 | 80 | 100 | V |
| Emitter-Base Voltage | V_{EBO} | 5.0 | | | V |
| Collector Current-Continuous -Peak | I_C I_{CM} | 8.0 15 | | | A |
| Base Current | I_B | 1.0 | | | A |
| Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 80 0.64 | | | W W/ $^\circ\text{C}$ |
| Operating and Storage Junction Temperature Range | T_J, T_{STG} | - 65 to +150 | | | $^\circ\text{C}$ |

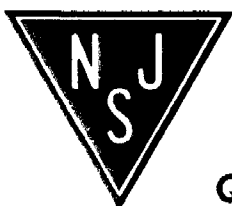
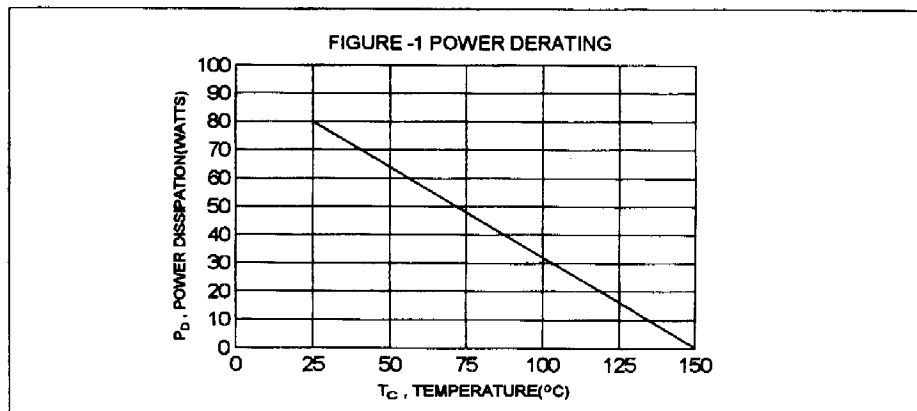


PN 1.BASE
2.COLLECTOR
3.EMITTER
4.COLLECTOR(CASE)

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|-------------------------------------|-----------------|------|--------------------|
| Thermal Resistance Junction to Case | $R_{\theta jc}$ | 1.56 | $^\circ\text{C/W}$ |

| DIM | MILLIMETERS | |
|-----|-------------|-------|
| | MIN | MAX |
| A | 14.68 | 15.31 |
| B | 9.78 | 10.42 |
| C | 5.01 | 6.52 |
| D | 13.06 | 14.62 |
| E | 3.57 | 4.07 |
| F | 2.42 | 3.66 |
| G | 1.12 | 1.36 |
| H | 0.72 | 0.96 |
| I | 4.22 | 4.98 |
| J | 1.14 | 1.38 |
| K | 2.20 | 2.97 |
| L | 0.33 | 0.55 |
| M | 2.48 | 2.98 |
| O | 3.70 | 3.90 |



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Quality Semi-Conductors

TIP100, TIP101, TIP102 NPN / TIP105, TIP106, TIP107 PNP

ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

OFF CHARACTERISTICS

| | | | | |
|--|--|---------------|-----------------|---------------|
| Collector - Emitter Sustaining Voltage (1) ($I_C = 30\text{ mA}, I_B = 0$) | TIP100, TIP105 TIP101, TIP106 TIP102, TIP107 | $V_{CE(sus)}$ | 60 80 100 | V |
| Collector Cutoff Current ($V_{CE} = 30\text{ V}, I_B = 0$) ($V_{CE} = 40\text{ V}, I_B = 0$) ($V_{CE} = 50\text{ V}, I_B = 0$) | TIP100, TIP105 TIP101, TIP106 TIP102, TIP107 | I_{CEO} | 50 50 50 | μA |
| Collector Cutoff Current ($V_{CB} = 60\text{ V}, I_E = 0$) ($V_{CB} = 80\text{ V}, I_E = 0$) ($V_{CB} = 100\text{ V}, I_E = 0$) | TIP100, TIP105 TIP101, TIP106 TIP102, TIP107 | I_{CBO} | 50 50 50 | μA |
| Emitter Cutoff Current ($V_{EB} = 5.0\text{ V}, I_C = 0$) | | I_{EBO} | 8.0 | mA |

ON CHARACTERISTICS (1)

| | | | | |
|---|---------------|-------------|------------|---|
| DC Current Gain ($I_C = 3.0\text{ A}, V_{CE} = 4.0\text{ V}$) ($I_C = 8.0\text{ A}, V_{CE} = 4.0\text{ V}$) | h_{FE} | 1000 200 | 20000 | |
| Collector-Emitter Saturation Voltage ($I_C = 3.0\text{ A}, I_B = 6.0\text{ mA}$) ($I_C = 8.0\text{ A}, I_B = 80\text{ mA}$) | $V_{CE(sat)}$ | | 2.0 2.5 | V |
| Base-Emitter On Voltage ($I_C = 8.0\text{ A}, V_{CE} = 4.0\text{ V}$) | $V_{BE(on)}$ | | 2.8 | V |

DYNAMIC CHARACTERISTICS

| | | | | |
|--|--|----------|------------|----|
| Small-Signal Current Gain ($I_C = 3.0\text{ A}, V_{CE} = 4.0\text{ V}, f = 1.0\text{ MHz}$) | h_{fe} | 4.0 | | |
| Output Capacitance ($V_{CB} = 10\text{ V}, I_E = 0, f = 0.1\text{ MHz}$) | TIP100, TIP101, TIP102 TIP105, TIP106, TIP107 | C_{ob} | 300 250 | pF |

(1) Pulse Test: Pulse width $\approx 300\text{ us}$, Duty Cycle $\leq 2.0\%$

